

Alexandria University Faculty of Engineering Division of Communications & Electronics

EE 432 VLSI Modeling and Design Lab#1: Physical Design and Layout of CMOS Inverter

Objectives

Upon the completion of this Lab, you should be able to:

- 1. Use L-edit software to lay out basic CMOS digital circuits,
- 2. Use T-spice software to analyze static and dynamic characteristics of CMOS digital circuits.

Requirements

You are required to draw the vertical and horizontal layouts for the basic CMOS inverter and compare between the two layouts in terms of the used area, power consumption, DC characteristics, and propagation delays. Both inverters should have the same dimensions.

The following sections provide the detailed procedures to draw the layout of the vertical CMOS inverter using L-edit.

Manual Layout

- Copy the following files into your directory Technology setup files for MOSIS/Orbit n-well 2.0 micron process. (Technology
 = SCNA, LAMBDA = 1.0 micron) C(tanner/ledit83/samples/tech/mosis/morbn20.
- 2. Launch L-Edit

3. Create New File. Create new files by choosing **File > New**, which opens the **New**

File dialog:

File type:	OK
Layout Text	Cancel
Copy TDB setup from file:	
Layout2	Browse
<empty></empty>	
Layout1	
Lauout2	

4. Replacing the Setup.

File > Replace Setup transfers setup information from a file (the *source* file) to the current file (the *destination* file).

From file:		OK
F:\TA\ece755\Tutorial\L	EDITTut\morbn20. Browse	Cancel
Layers Layers Replace Merge CIF names GDS II Wire settings	Design Technology Maintain physical size Rescale Draw Selection Palette Grid Show/Hides Yref files Properties	Uncheck Al
Modules V DRC rules SPR V Core setup V Padframe setup BPR	Extract IC Cross-Section Pad route setup Place and Route configuration	

5. Under Setup -> Design

The chosen technology units should be lambda It should be 1 internal unit for 1/1000 lambda The lambda value should be 1 microns

Grid -> Grid Display -> Displayed Grid 0.5 locator units

Setup Design	X Setup Design
Technology Grid Selection Drawing Curves Xref files	Technology Grid Selection Drawing Curves Xref files
MOSIS/ORBIT 2.0u SCNA Technology units O Microns O Millimeters O Microns O Millimeters	Grid display Displayed grid: Locator Units Suppress grid less than: 8 Pixels
C Miles C Inches • Uther: Lambda	Mouse grid Cursor type: I Snapping C Smooth Mouse snap grid: 0.500 Locator Units
1 Internal Unit = 1 1000 Lambda	Locator Units One Locator Unit: 1000 Internal Units
1 Lambda = $\frac{1}{1}$ Microns	
OK Cancel	DK Cancel

- 6. Create a new cell. Cell -> New, call it inv
- 7. Draw 14 x 6 λ **Active** Box.

8. Draw two 4 x 4 λ Metal1 box and put on both sides of Active box.

9. Draw two 2 x 2 λ Active Contact centered on each Metal 1 box It looks like.



- 10. Draw 10 x 2 λ poly box centered at the active.
- 11. Draw 18 x 23 λ N Select.



12. Copy the whole block above, select N Select and click Edit -> Edit Object, change

N Select to be P Select.

- 13. Draw 10 x 18 λ P Select below the Nselect of NMOS.
- 14. Draw 6 x 6 λ Active inside the Pselect.
- 15. Draw 2 x 2 λ Active Contact inside the Active
- 16. Extend the Metal1 to Pselect area, it looks like:



17. With the same method draw a Nselect on the top of PMOS





18. Draw 25 x 40 λ Nwell at PMOS place.





19. Connect following the inverter schematic.



- 20. Draw 5 x 6 λ Poly beside the gate of two transistors.
- 21. Draw 4 x 4 λ Metal 1 centered in the poly.
- 22. Draw 2 x 2 λ Poly Contact centered in the Metal1



23. Click Port A on the Toolbar. And draw OUT port. The dialog jumps out. On Layer: Metal1 Port name: OUT

		1
oxes Polygons Tori Port	Wires Circles Pie Wea ts (1) Rulers Instanc	lge: es
	·	
Port name: [UUT		
Text size: [2.50	0 🛨 Locator Units	
Coordinates (Locator L	Jnits) Text Alignment	
X1: 11.500		е
×1: -11.500 ×2: -9.000	Abovi Abovi Abovi Abovi Abovi Abovi	e e
X1: -11.500 X2: -9.000 Y1: 89.500	A C C C Abov.	e e /
X1: -11.500 X2: -9.000 Y1: 89.500	C C C Abov C C C Middl C C C Belov Left Center Right	e e ,

24. With the same method draw port for IN, VDD, GND. On Layer: Metal1, Port name:IN/VDD/GND. It looks like



25. Run DRC check

A dialog box jumps out.

	te	
Log file:	do .	
Write errors to	file	
☐ Write detailed	timing statistics to file	
inv.drc	Browse.	
Bin size: 50.000	L ocator Units	
	Ecodior Office	

- 26. If No DRC error, go to next step. If there is any, open the file inv.drc or click to see the error. If you don't like the error displayed on the screen, click on the bar.
- 27. Extract the file to be SPICE file. Click 🖾 on the toolbar. A dialog jumps out. Fill the form as following then click RUN.

Extract	Extract	×
Extract definition file:	Comments Write node names Write device coordinates (Locator Units) Write shorted devices Write layer capacitance and resistance war	Write nodes and devices as C Integers C Names nings
Inv.spc Browse Recognition Layer	Format Nodal parasitic capacitance Write values in scientific notation Write nodal parasitic capacitance Write verbose SPICE statements Ignore nodal parasitic capacitance Write empty subcircuit definitions Femtofarads Write .END statement 5	
Bin size: 100.000 Locator Units Run Cancel Accept	SPICE include statement: include "G:\WIN32\TannerT\models\ml2_20	I.md"

28. Launch T-Spice to run simulation. The Spice file looks like

* Circuit Extracted by Tanner Research's L-Edit Version 8.30 / Extract Version 8.30 ;

- * TDB File: F:\TA\ece755\Tutorial\LEDITTut\inv.tdb
- * Cell: inv Version 1.24
- * Extract Definition File: morbn20.ext
- * Extract Date and Time: 09/28/2001 10:26

.include "G:\WIN32\TannerT\models\ml2_20.md"

- * Warning: Layers with Unassigned AREA Capacitance.
- * <P Base Resistor>

- * <N Well Resistor>
- * <P Diff Resistor>
- * <N Diff Resistor>
- * <Poly2 Resistor>
- * <Poly Resistor>
- * Warning: Layers with Unassigned FRINGE Capacitance.
- * <Poly1-Poly2 Capacitor>
- * <P Base Resistor>
- * <N Well Resistor>
- * <P Diff Resistor>
- * <N Diff Resistor>
- * <Poly2 Resistor>
- * <Poly Resistor>
- * <Pad Comment>
- * Warning: Layers with Zero Resistance.
- * <PMOS Capacitor>
- * <NMOS Capacitor>
- * <Poly1-Poly2 Capacitor>
- * <Pad Comment>

* NODE NAME ALIASES

- * 1 = IN (-56.5,90)
- * 2 = OUT (-11.5,89.5)
- * 3 = VDD (-34,119)
- * 4 = GND (-34,65)

M1 OUT IN VDD VDD PMOS L=2u W=6u AD=36p PD=24u AS=36p PS=24u * M1 DRAIN GATE SOURCE BULK (-36 107 -30 109) M2 GND IN OUT GND NMOS L=2u W=6u AD=36p PD=24u AS=36p PS=24u * M2 DRAIN GATE SOURCE BULK (-36 74.5 -30 76.5)

* Total Nodes: 4

* Total Elements: 2

- * Total Number of Shorted Elements not written to the SPICE file: 0
- * Extract Elapsed Time: 0 seconds
- .END

Pay attention to the sequence of the MOSFET connection to ensure it is drain, gate, source and base

29. Add the running command and run simulation.

- * Circuit Extracted by Tanner Research's L-Edit Version 8.30 / Extract Version 8.30 ;
- * TDB File: F:\TA\ece755\Tutorial\LEDITTut\inv.tdb
- * Cell: inv Version 1.24
- * Extract Definition File: morbn20.ext
- * Extract Date and Time: 09/28/2001 10:26

.include "G:\WIN32\TannerT\models\ml2_20.md"

- * Warning: Layers with Unassigned AREA Capacitance.
- * <P Base Resistor>
- * <N Well Resistor>
- * <P Diff Resistor>
- * <N Diff Resistor>
- * <Poly2 Resistor>

- * <Poly Resistor>
- * Warning: Layers with Unassigned FRINGE Capacitance.
- * <Poly1-Poly2 Capacitor>
- * <P Base Resistor>
- * <N Well Resistor>
- * <P Diff Resistor>
- * <N Diff Resistor>
- * <Poly2 Resistor>
- * <Poly Resistor>
- * <Pad Comment>

* Warning: Layers with Zero Resistance.

- * <PMOS Capacitor>
- * <NMOS Capacitor>
- * <Poly1-Poly2 Capacitor>
- * <Pad Comment>

* NODE NAME ALIASES

- * 1 = IN (-56.5,90)
- * 2 = OUT (-11.5,89.5)
- * 3 = VDD (-34,119)
- * 4 = GND (-34,65)

M1 OUT IN VDD VDD PMOS L=2u W=6u AD=36p PD=24u AS=36p PS=24u * M1 DRAIN GATE SOURCE BULK (-36 107 -30 109) M2 GND IN OUT GND NMOS L=2u W=6u AD=36p PD=24u AS=36p PS=24u * M2 DRAIN GATE SOURCE BULK (-36 74.5 -30 76.5)

Vin IN GND PULSE (0 5 0 1n 1n 100n 200n) Vdd VDD GND 5

.tran/powerup 5n 500n method=bdf .print tran v(IN) v(OUT)

- * Total Nodes: 4
- * Total Elements: 2
- * Total Elements: 2
- * Total Number of Shorted Elements not written to the SPICE file: 0
- * Extract Elapsed Time: 0 seconds

.END